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FAIRCHILD SEMICONDUCTOR®

December 2010

FLS-XS Series — Half-Bridge LLC Resonant Control IC for Lighting

Features

- Variable Frequency Control with 50% Duty Cycle for Half-Bridge Resonant Converter Topology
- High Efficiency through Zero Voltage Switching (ZVS)
- Internal UniFET™ with Fast-Recovery Body Diode
- Fixed Dead Time (350ns) Optimized for MOSFETs
- Up to 300kHz Operating Frequency
- Auto-Restart Operation for All Protections with External LV_{CC}
- Protection Functions: Over-Voltage Protection (OVP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD)

Applications

- General LED Lighting Power
- Industrial, Commercial, and Residential LED Lighting Fixtures
- Outdoor Lighting: Street, Roadway, Parking, Construction and Ornamental LED Lighting Fixtures

Description

The FLS-XS series of general lighting power controllers includes highly integrated power switches for medium- to high-power lumens applications. Offering everything necessary to build a reliable and robust half-bridge resonant converter, the FLS-XS series simplifies designs and improves productivity, while improving performance. The FLS-XS series combines power MOSFETs with fast-recovery type body diodes, a high-side gate-drive circuit, an accurate current controlled oscillator, frequency limit circuit, soft-start, and built-in protection functions. The high-side gate-drive circuit has common-mode noise cancellation capability, which guarantees stable operation with excellent noise immunity. The fast-recovery body diode of the MOSFETs improves reliability against abnormal operation conditions, while minimizing the effect of reverse recovery. Using zero voltage switching (ZVS) dramatically reduces the switching losses and significantly improves efficiency. ZVS also reduces switching noise noticeably, which allows a small-sized Electromagnetic Interference (EMI) filter.

The FLS-XS series can be applied to resonant converter topologies such as series resonant, parallel resonant, and LLC resonant converters.

Ordering Information

Part Number	Package	Operating Junction Temperature	$R_{DS(ON\_MAX)}$	Maximum Output Power without Heatsink (V_{IN}=350~400V)(1,2)	Maximum Output Power with Heatsink (V_{IN}=350~400V)(1,2)
FLS2100XS	9-SIP	-40 to +130°C	0.51Ω	180W	400W
FLS1800XS			0.95Ω	120W	260W
FLS1700XS			1.25Ω	100W	200W
FLS1600XS			1.55Ω	80W	160W

Notes:
1. The junction temperature can limit the maximum output power.
2. Maximum practical continuous power in an open-frame design at 50°C ambient.

Application Circuit Diagram

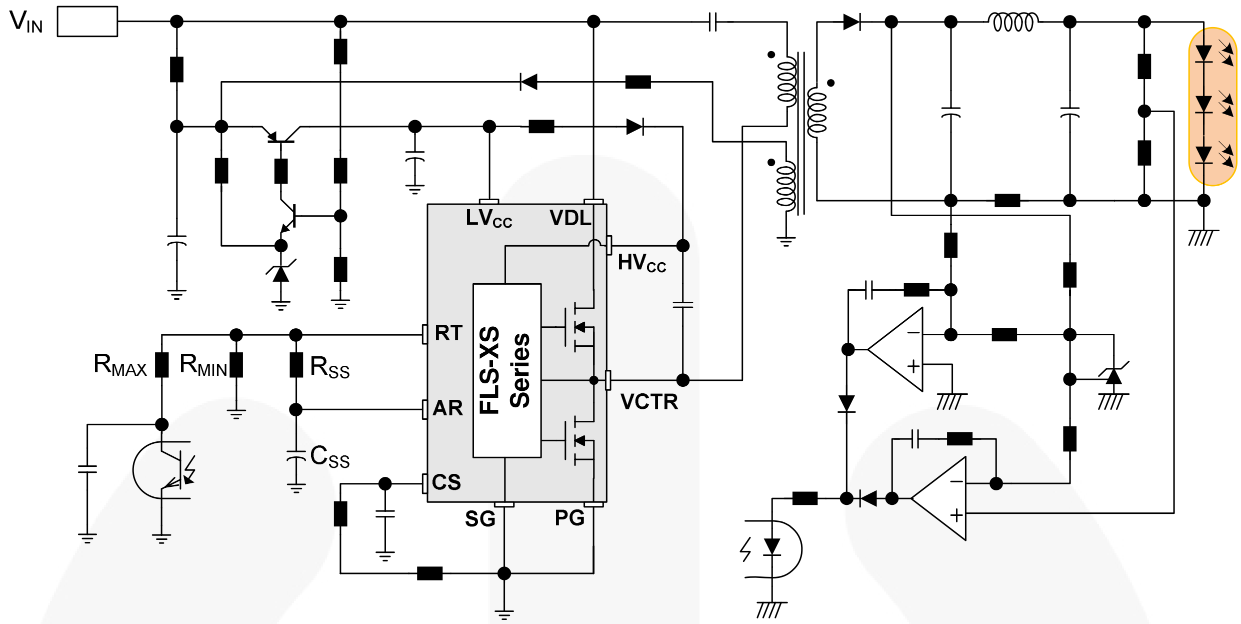


Figure 1. Typical Application Circuit for LLC Resonant Half-Bridge Converter

Block Diagram

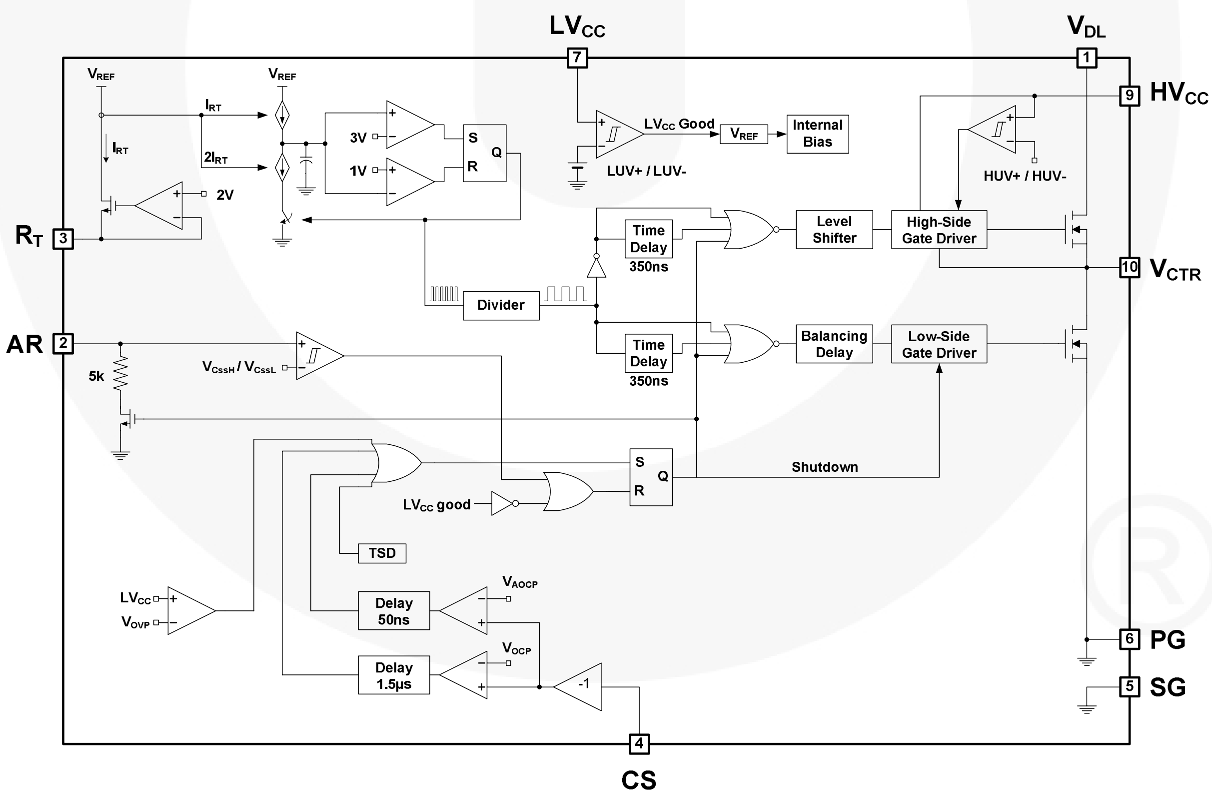


Figure 2. Internal Block Diagram

Pin Configuration

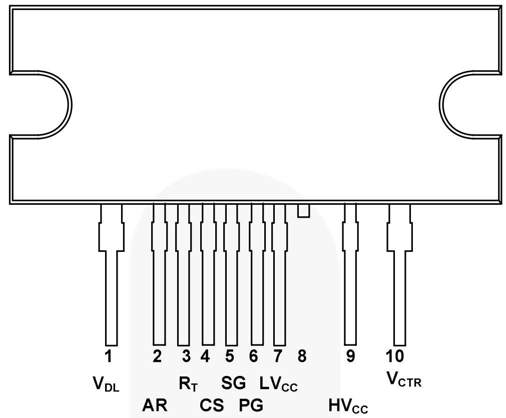


Figure 3. Package Diagram

Pin Definitions

Pin #	Name	Description
1	V_{DL}	This is the drain of the high-side MOSFET, typically connected to the input DC link voltage.
2	AR	This pin is for discharging the external soft-start capacitor when any protections are triggered. When the voltage of this pin drops to 0.2V, all protections are reset and the controller starts to operate again.
3	R_T	This pin programs the switching frequency. Typically, an opto-coupler is connected to control the switching frequency for the output voltage regulation.
4	CS	This pin senses the current flowing through the low-side MOSFET. Typically, negative voltage is applied on this pin.
5	SG	This pin is the control ground.
6	PG	This pin is the power ground. This pin is connected to the source of the low-side MOSFET.
7	LV_{CC}	This pin is the supply voltage of the control IC.
8	NC	No connection
9	HV_{CC}	This is the supply voltage of the high-side gate-drive circuit IC.
10	V_{CTR}	This is the drain of the low-side MOSFET. Typically, a transformer is connected to this pin.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. T_A=25°C unless otherwise specified.

Symbol	Parameter			Min.	Max.	Unit
V_{DS}	Maximum Drain-to-Source Voltage (V_{DL}-V_{CTR} and V_{CTR}-PG)			500		V
LV_{CC}	Low-Side Supply Voltage			-0.3	25.0	V
HV_{CC} to V_{CTR}	High-Side V_{CC} Pin to Low-Side Drain Voltage			-0.3	25.0	V
HV_{CC}	High-Side Floating Supply Voltage			-0.3	525.0	V
V_{AR}	Auto-Restart Pin Input Voltage			-0.3	LV_{CC}	V
V_{CS}	Current-Sense (CS) Pin Input Voltage			-5.0	1.0	V
V_{RT}	R_T Pin Input Voltage			-0.3	5.0	V
dV_{CTR}/dt	Allowable Low-Side MOSFET Drain Voltage Slew Rate				50	V/ns
P_D	Total Power Dissipation[3]	FLS2100XS			12.0	W
		FLS1800XS			11.7	
		FLS1700XS			11.6	
		FLS1600XS			11.5	
T_J	Maximum Junction Temperature[4]				+150	°C
	Recommended Operating Junction Temperature[4]			-40	+130	
T_{STG}	Storage Temperature Range			-55	+150	°C
MOSFET Section						
V_{DGR}	Drain Gate Voltage (R_{GS}=1MΩ)			500		V
V_{GS}	Gate Source (GND) Voltage				±30	V
I_{DM}	Drain Current Pulsed[5]	FLS2100XS			32	A
		FLS1800XS			23	
		FLS 1700XS			20	
		FLS 1600XS			18	
I_D	Continuous Drain Current	FLS2100XS	T_C=25°C		10.5	A
			T_C=100°C		6.5	
		FLS1800XS	T_C=25°C		7.0	
			T_C=100°C		4.5	
		FLS 1700XS	T_C=25°C		6.0	
			T_C=100°C		3.9	
		FLS 1600XS	T_C=25°C		4.5	
			T_C=100°C		2.7	
Package Section						
Torque	Recommended Screw Torque			5~7		kgf·cm

Notes:

3. Per MOSFET when both MOSFETs are conducting.
4. The maximum value of the recommended operating junction temperature is limited by thermal shutdown.
5. Pulse width is limited by maximum junction temperature.

Thermal Impedance

T_A=25°C unless otherwise specified.

Symbol	Parameter		Value	Unit
θ_{JC}	Junction-to-Case Center Thermal Impedance (Both MOSFETs Conducting)	FLS2100XS	10.44	ºC/W
		FLS1800XS	10.68	
		FLS 1700XS	10.79	
		FLS 1600XS	10.89	

Electrical Characteristics

T_A=25°C unless otherwise specified.

Symbol	Parameter		Test Conditions	Min.	Typ.	Max.	Unit
MOSFET Section							
BV_{DSS}	Drain-to-Source Breakdown Voltage		I_D=200μA, T_A=25°C	500			V
			I_D=200μA, T_A=125°C		540		
$R_{DS(ON)}$	On-State Resistance	FLS2100XS	V_{GS}=10V, I_D=6.0A		0.41	0.51	Ω
		FLS1800XS	V_{GS}=10V, I_D=3.0A		0.77	0.95	
		FLS 1700XS	V_{GS}=10V, I_D=2.0A		1.00	1.25	
		FLS 1600XS	V_{GS}=10V, I_D=2.25A		1.25	1.55	
t_{rr}	Body Diode Reverse Recovery Time(6)	FLS2100XS	V_{GS}=0V, I_{Diode}=10.5A, dI_{Diode}/dt=100A/μs		120		ns
		FLS1800XS	V_{GS}=0V, I_{Diode}=7.0A, dI_{Diode}/dt=100A/μs		160		
		FLS 1700XS	V_{GS}=0V, I_{Diode}=6.0A, dI_{Diode}/dt=100A/μs		160		
		FLS 1600XS	V_{GS}=0V, I_{Diode}=5.0A, dI_{Diode}/dt=100A/μs		65		
Supply Section							
I_{LK}	Offset Supply Leakage Current		HV_{CC}=V_{CTR}=500V			50	μA
I_QHV_{CC}	Quiescent HV_{CC} Supply Current		$(HV_{CC}UV+)$ - 0.1V		50	120	μA
I_QLV_{CC}	Quiescent LV_{CC} Supply Current		$(LV_{CC}UV+)$ - 0.1V		100	200	μA
I_OHV_{CC}	Operating HV_{CC} Supply Current (RMS Value)		f_{OSC}=100KHz		6	9	mA
			No Switching		100	200	μA
I_OLV_{CC}	Operating LV_{CC} Supply Current (RMS Value)		f_{OSC}=100KHz		7	11	mA
			No Switching		2	4	mA

Continued on the following page…

Electrical Characteristics

T_A=25°C unless otherwise specified.

UVLO Section						
$LV_{CC}UV+$	LV_{CC} Supply Under-Voltage Positive-Going Threshold (LV_{CC} Start)		11.2	12.5	13.8	V
$LV_{CC}UV-$	LV_{CC} Supply Under-Voltage Negative-Going Threshold (LV_{CC} Stop)		8.9	10.0	11.1	V
$LV_{CC}UVH$	LV_{CC} Supply Under-Voltage Hysteresis			2.50		V
$HV_{CC}UV+$	HV_{CC} Supply Under-Voltage Positive-Going Threshold (HV_{CC} Start)		8.2	9.2	10.2	V
$HV_{CC}UV-$	HV_{CC} Supply Under-Voltage Negative-Going Threshold (HV_{CC} Stop)		7.8	8.7	9.6	V
$HV_{CC}UVH$	HV_{CC} Supply Under-Voltage Hysteresis			0.5		V
Oscillator & Feedback Section						
V_{RT}	V-I Converter Threshold Voltage	R_T=5.2KΩ	1.5	2.0	2.5	V
f_{OSC}	Output Oscillation Frequency		94	100	106	KHz
DC	Output Duty Cycle		48	50	52	%
f_{SS}	Internal Soft-Start Initial Frequency	f_{SS}=f_{OSC}+40kHz, R_T=5.2KΩ		140		KHz
t_{SS}	Internal Soft-Start Time		2	3	4	ms
Protection Section						
V_{CssH}	Beginning Voltage to Discharge C_{SS}		0.9	1.0	1.1	V
V_{CssL}	Beginning Voltage to Charge C_{SS} and Restart		0.16	0.20	0.24	V
V_{OVP}	LV_{CC} Over-Voltage Protection	LV_{CC} > 21V	21	23	25	V
V_{AOCP}	AOCP Threshold Voltage		-1.0	-0.9	-0.8	V
t_{BAO}	AOCP Blanking Time(6)	V_{CS} < V_{AOCP}		50		ns
V_{OCP}	OCP Threshold Voltage		-0.64	-0.58	-0.52	V
t_{BO}	OCP Blanking Time(6)	V_{CS} < V_{OCP}	1.0	1.5	2.0	μs
t_{DA}	Delay Time (Low Side) Detecting from V_{AOCP} to Switch Off(6)			250	400	ns
T_{SD}	Thermal Shutdown Temperature(6)		+120	+135	+150	°C
Dead-Time Control Section						
D_T	Dead Time(7)			350		ns

Notes:
6. This parameter, although guaranteed by design, is not tested in production.
7. These parameters, although guaranteed, are tested only in EDS (wafer test) process.

Typical Performance Characteristics

These characteristic graphs are normalized at T_A=25ºC.

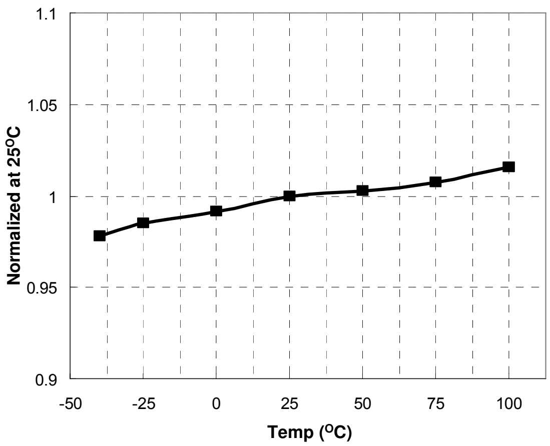


Figure 4. Low-Side MOSFET Duty Cycle vs. Temperature

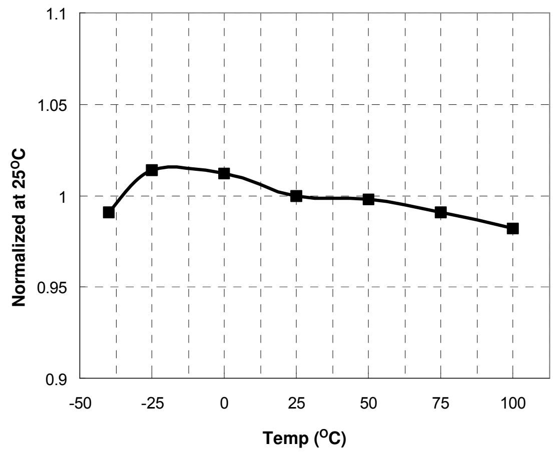


Figure 5. Switching Frequency vs. Temperature

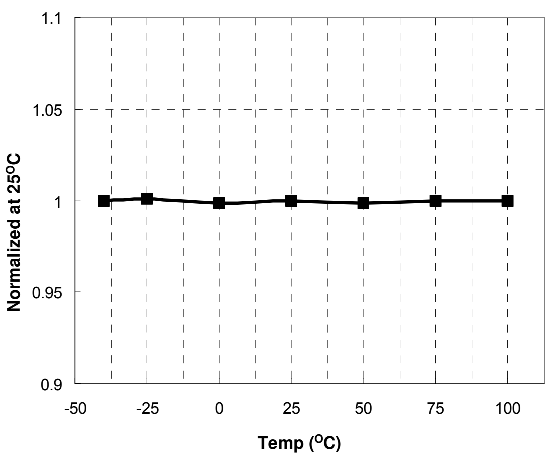


Figure 6. High-Side V_{CC} (HV_{CC}) Start vs. Temperature

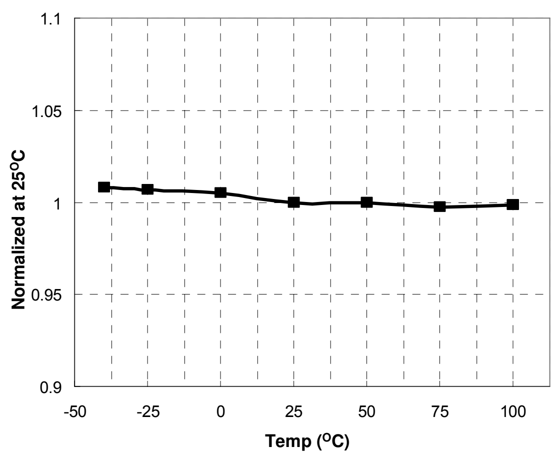


Figure 7. High-Side V_{CC} (HV_{CC}) Stop vs. Temperature

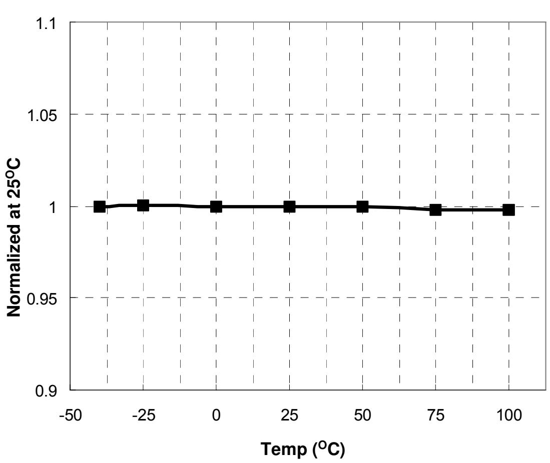


Figure 8. Low-Side V_{CC} (LV_{CC}) Start vs. Temperature

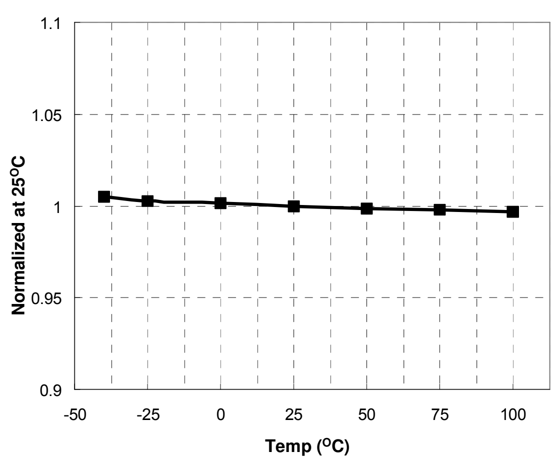


Figure 9. Low-Side V_{CC} (LV_{CC}) Stop vs. Temperature

Typical Performance Characteristics (Continued)

These characteristic graphs are normalized at T_A=25ºC.

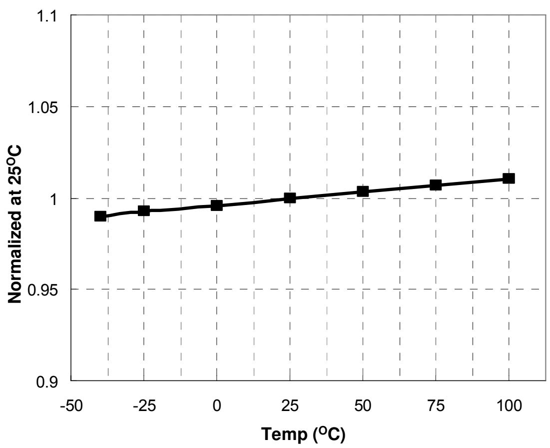


Figure 10. LV_{CC} OVP Voltage vs. Temperature

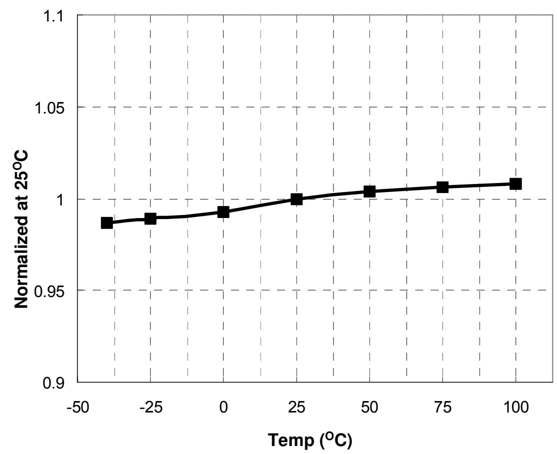


Figure 11. R_T Voltage vs. Temperature

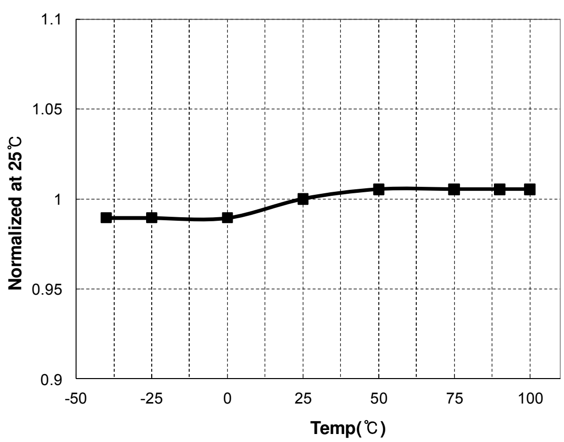


Figure 12. V_{CssL} vs. Temperature

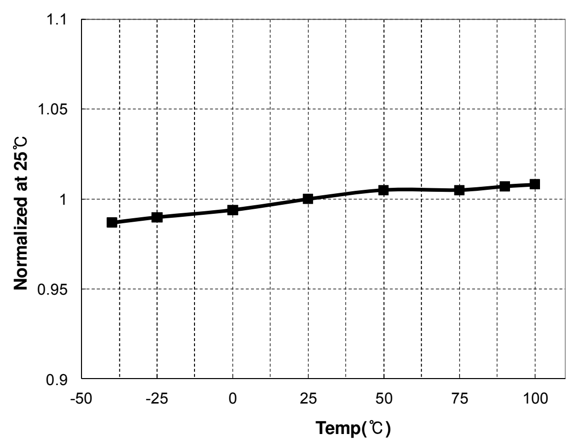


Figure 13. V_{CssH} vs. Temperature

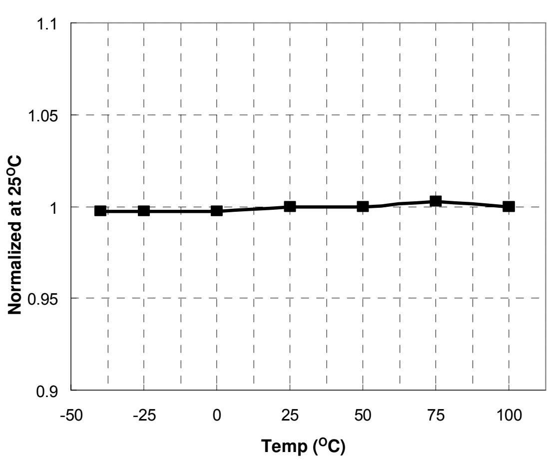


Figure 14. OCP Voltage vs. Temperature

Functional Description

1. Basic Operation. FLS-XS series is designed to drive high-side and low-side MOSFETs complementarily with 50% duty cycle. A fixed dead time of 350ns is introduced between consecutive transitions, as shown in Figure 15.

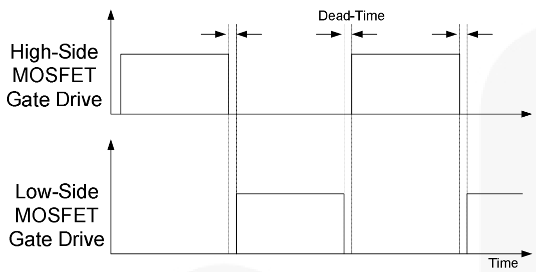


Figure 15. MOSFETs Gate Drive Signal

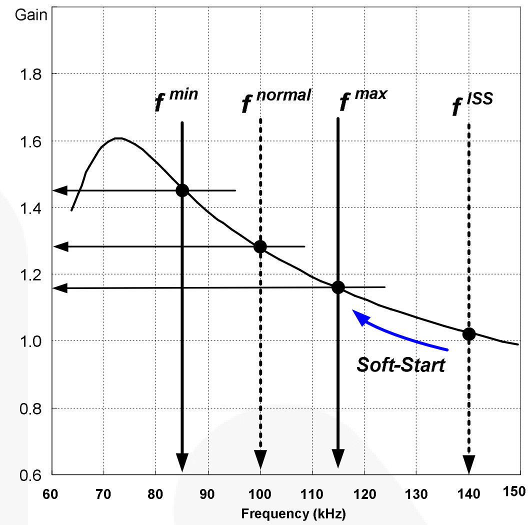


Figure 17. Resonant Converter Typical Gain Curve

2. Internal Oscillator: FLS-XS series employs a current-controlled oscillator, as shown in Figure 16. Internally, the voltage of the R_T pin is regulated at 2V and the charging / discharging current for the oscillator capacitor, C_T, is obtained by copying the current flowing out of the R_T pin (I_{CTC}) using a current mirror. Therefore, the switching frequency increases as I_{CTC} increases.

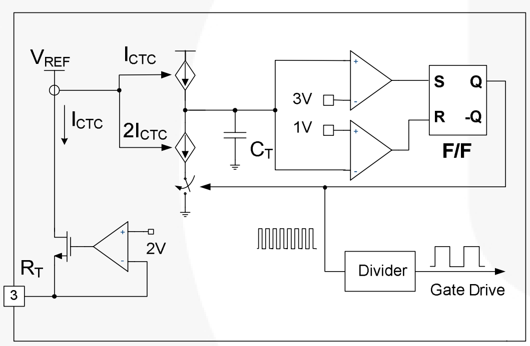


Figure 16. Current-Controlled Oscillator

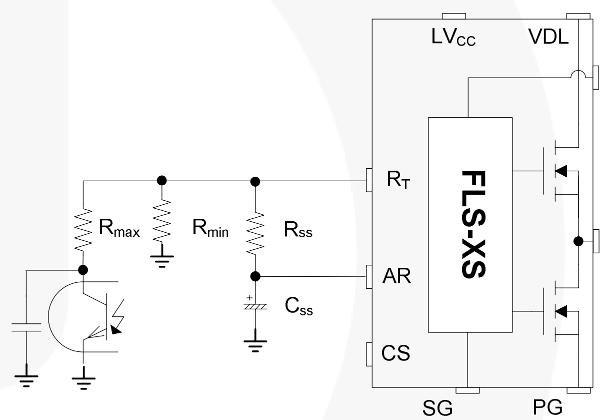


Figure 18. Frequency Control Circuit

3. Frequency Setting: Figure 17 shows the typical voltage gain curve of a resonant converter, where the gain is inversely proportional to the switching frequency in the ZVS region. The output voltage can be regulated by modulating the switching frequency. Figure 18 shows the typical circuit configuration for the R_T pin, where the opto-coupler transistor is connected to the R_T pin to modulate the switching frequency.

The minimum switching frequency is determined as:

$$f^{\min} = \frac{5.2k\Omega}{R_{\min}} \times 100(kHz) \tag{1}$$

Assuming the saturation voltage of opto-coupler transistor is 0.2V, the maximum switching frequency is determined as:

$$f^{\max} = \left(\frac{5.2k\Omega}{R_{\min}} + \frac{4.68k\Omega}{R_{\max}}\right) \times 100(kHz) \tag{2}$$

To prevent excessive inrush current and overshoot of output voltage during startup, increase the voltage gain of the resonant converter progressively. Since the voltage gain of the resonant converter is inversely proportional to the switching frequency, the soft-start is implemented by sweeping down the switching frequency from an initial high frequency (f^{ISS}) until the output voltage is established. The soft-start circuit is made by connecting R-C series network on the R_T pin, as shown in Figure 18. FLS-XS series also has a 3ms internal soft-start to reduce the current overshoot during the initial cycles, which adds 40kHz to the initial frequency of the external soft-start circuit, as shown in Figure 19. The initial frequency of the soft-start is given as:

$$f^{ISS} = \left(\frac{5.2k\Omega}{R_{\min}} + \frac{5.2k\Omega}{R_{SS}}\right) \times 100 + 40\ (kHz) \tag{3}$$

It is typical to set the initial frequency of soft-start two to three times the resonant frequency (f_O) of the resonant network. The soft-start time is three to four times the RC time constant. The RC time constant is:

$$\tau = R_{SS} \bullet C_{SS} \tag{4}$$

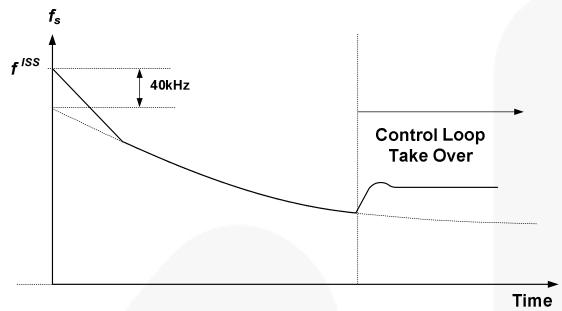


Figure 19. Frequency Sweeping of Soft-Start

4. Self Auto-Restart: The FLS-XS series can restart automatically even when any built-in protections are triggered with external supply voltage. As can be seen in Figure 20 and Figure 21, once a protection is triggered, the M1 switch turns on and the V-I converter is disabled. C_{SS} starts to discharge until V_{Css} across C_{SS} drops to V_{CssL}. Then, all protections are reset, M1 turns off, and the V-I converter resumes. The FLS-XS starts switching again with soft-start. If the protections occur while V_{Css} is under V_{CssL} and V_{CssH} level, the switching is terminated immediately, V_{Css} continues to increase until reaching V_{CssH}, then C_{SS} is discharged by M1.

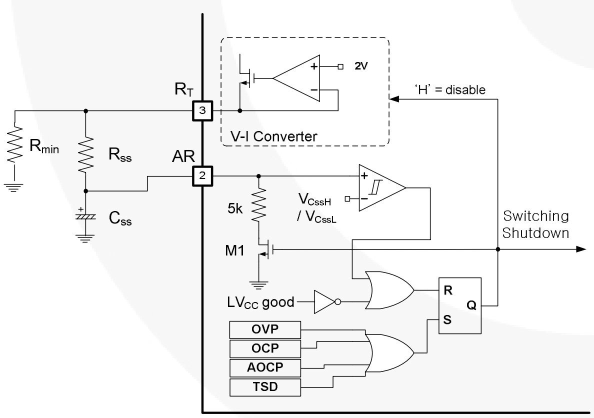
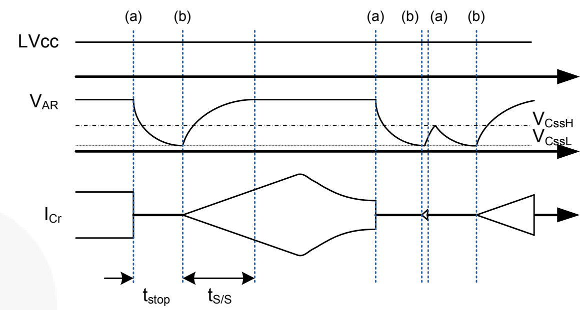


Figure 20. Internal Block of AR Pin

After protections trigger, FLS-XS is disabled during the stop-time, t_{stop}, where V_{Css} decreases and reaches to V_{CssL}. The stop-time of FLS-XS can be estimated as:

$$t_{STOP} = C_{SS} \bullet \{(R_{SS} + R_{MIN}) \| 5k\Omega\} \tag{5}$$

The soft-start time $t_{s/s}$ can be set from Equation (4).



(a) Protections are triggered, (b) FLS-XS restarts

Figure 21. Self Auto-Restart Operation

5. Protection Circuits: The FLS-XS series has several self-protective functions, such as Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). These protections are auto-restart-mode protections, as shown in Figure 22.

Once a fault condition is detected, switching is terminated and the MOSFETs remain off. When LV_{CC} falls to the LV_{CC} stop voltage of 10V or AR signal is HIGH, the protection is reset. The FLS-XS resumes normal operation when LV_{CC} reaches the start voltage of 12.5V.

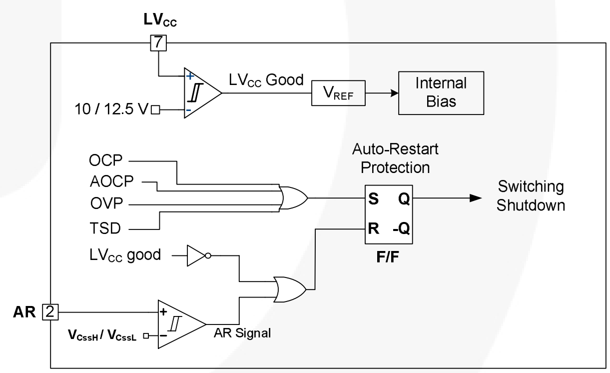


Figure 22. Protection Blocks

5.1 Over-Current Protection (OCP): When the sensing pin voltage drops below -0.58V, OCP is triggered and the MOSFETs remain off. This protection has a shutdown time delay of 1.5µs to prevent premature shutdown during startup.

5.2 Abnormal Over-Current Protection (AOCP): If the secondary rectifier diodes are shorted, large current with extremely high di/dt can flow through the MOSFET before OCP is triggered. AOCP is triggered without shutdown delay if the sensing pin voltage drops below -0.9V.

5.3 Over-Voltage Protection (OVP): When the LV_{CC} reaches 23V, OVP is triggered. This protection is used when auxiliary winding of the transformer to supply V_{CC} to the FPS™ is utilized.

5.4 Thermal Shutdown (TSD): Having the MOSFETs and the control IC in one package makes it easier for the control IC to detect the abnormal over-temperature of the MOSFETs. If the temperature exceeds approximately 130°C, thermal shutdown triggers.

6. Current Sensing Using a Resistor: FLS-XS series senses drain current as a negative voltage, as shown in Figure 23 and Figure 24. Half-wave sensing allows low power dissipation in the sensing resistor; while full-wave sensing has less switching noise in the sensing signal.

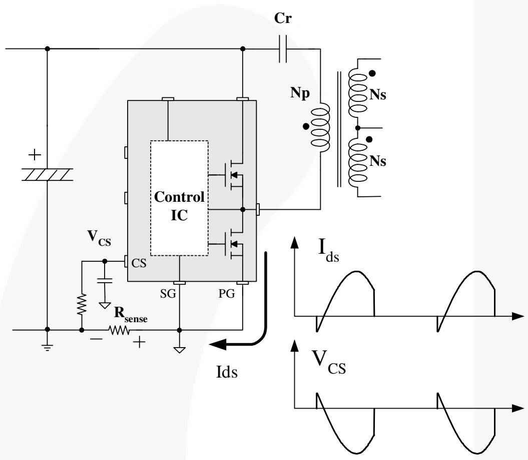


Figure 23. Half-Wave Sensing

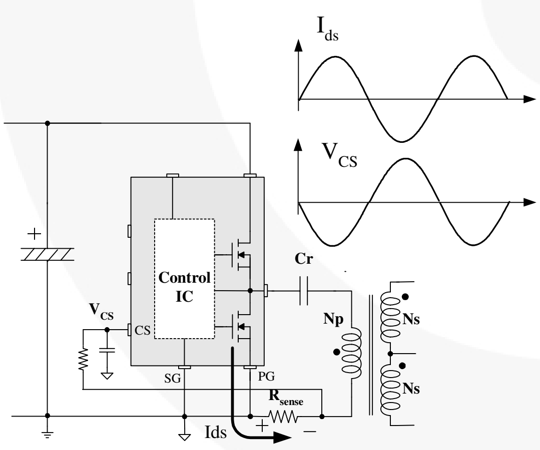


Figure 24. Full-Wave Sensing

7. PCB Layout Guidelines: Duty imbalance problems may occur due to the radiated noise from the main transformer, the inequality of the secondary side-leakage inductances of main transformer, and so on. This is one of the reasons that the control components in the vicinity of R_T pin are enclosed by the primary current flow pattern on PCB layout. The direction of the magnetic field on the components caused by the primary current flow is changed when the high- and low-side MOSFET turn on by turns. The magnetic fields with opposite directions induce a current through, into, or out of the R_T pin, which changes the turn-on duration of each MOSFET. It is strongly recommended to separate the control components in the vicinity of R_T pin from the primary current flow pattern on PCB layout. Figure 25 shows an example for the duty-balanced case.

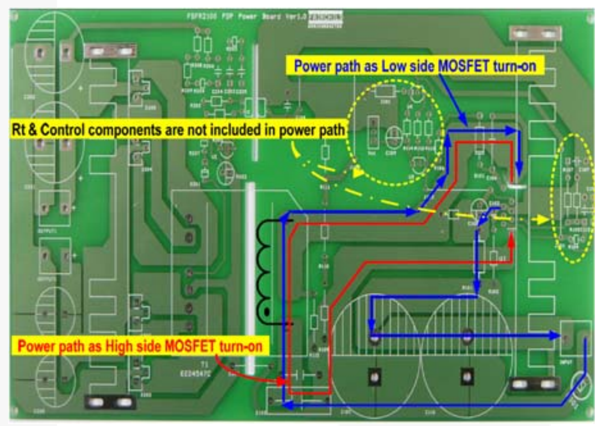


Figure 25. Example for Duty Balancing

Physical Dimensions

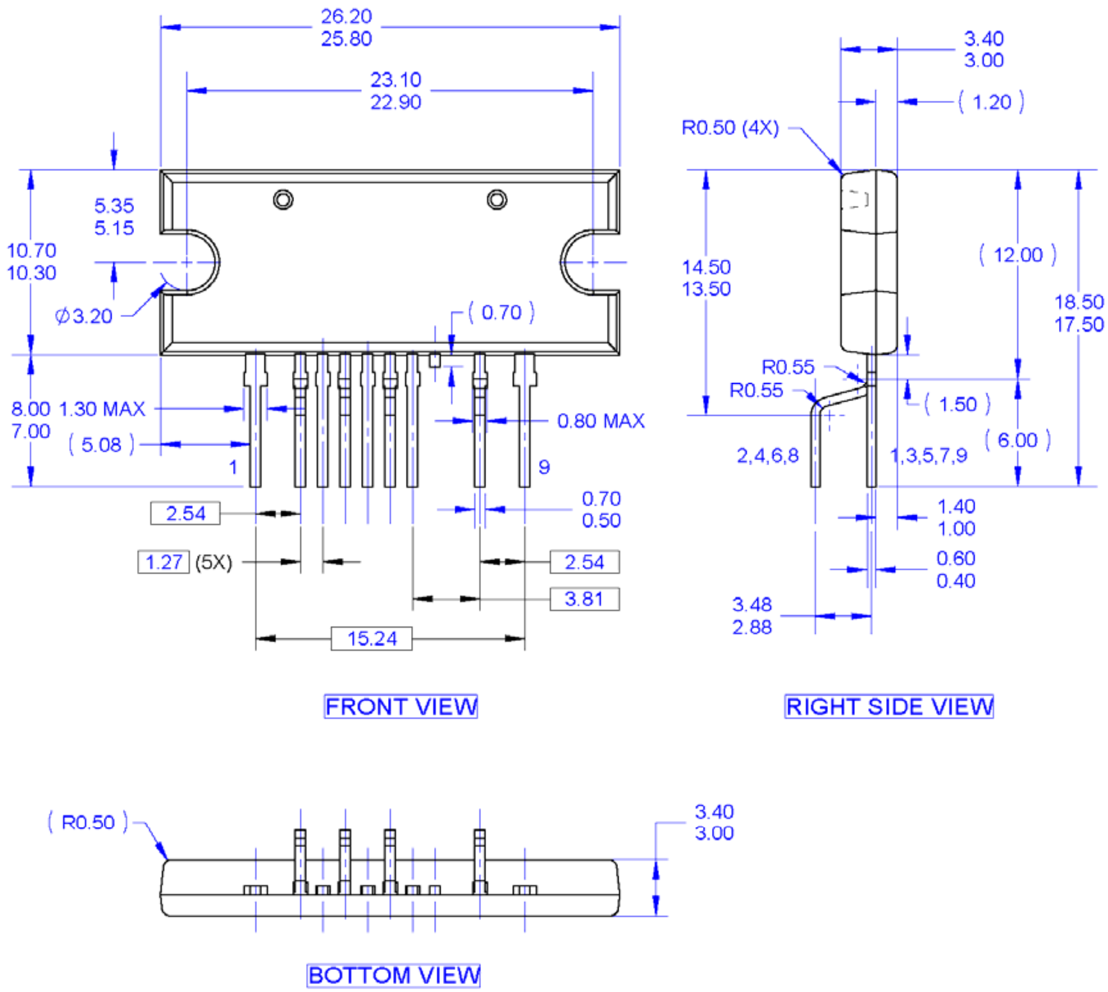


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Figure 26. 9-Lead Single Inline Package (SIP)

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